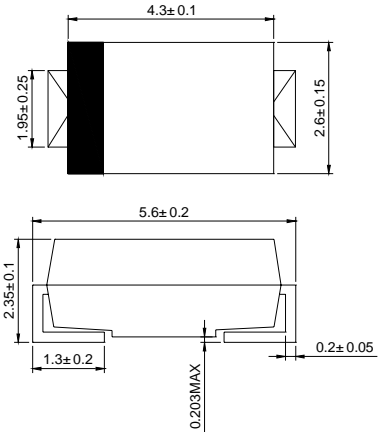


VOLTAGE RANGE: 50 --- 1000 V

CURRENT: 1.0 A



SMAJ



Dimensions in millimeters

Features

- ◇ Low cost
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

Mechanical Data

- ◇ Case: JEDEC SMAJ, molded plastic
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.003 ounces, 0.084 grams
- ◇ Mounting position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

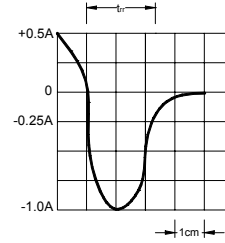
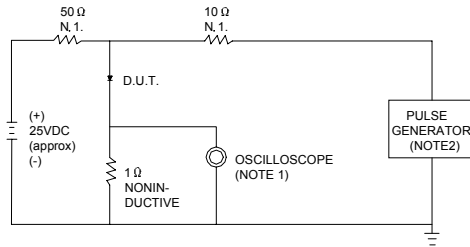
Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		UF1AJ	UF1BJ	UF1DJ	UF1GJ	UF1JJ	UF1KJ	UF1MJ	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current @ $T_L=90^\circ\text{C}$	$I_{F(AV)}$	1.0							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	I_{FSM}	30							A
Maximum instantaneous forward voltage at 1.0 A	V_F	1.0		1.4		1.7		V	
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	10 100							μA
Typical reverse recovery time (Note1)	t_{rr}	50				75		ns	
Typical junction capacitance (Note2)	C_J	15				12		pF	
Typical thermal resistance (Note3)	$R_{\theta JA}$	15							$^\circ\text{C/W}$
Operating junction temperature range	T_J	- 55 ---- + 150							$^\circ\text{C}$
Storage temperature range	T_{STG}	- 55 ---- + 150							$^\circ\text{C}$

NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$.

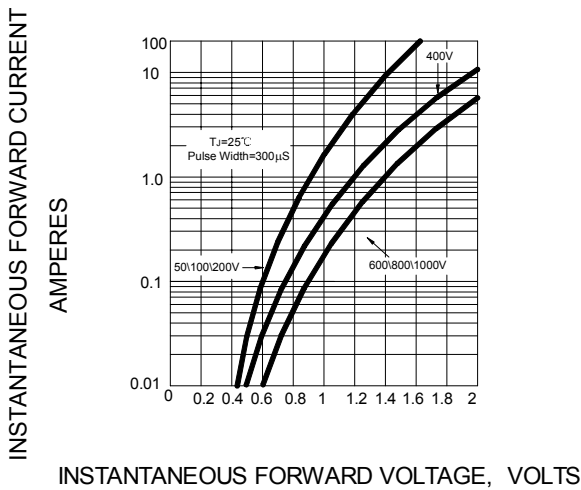
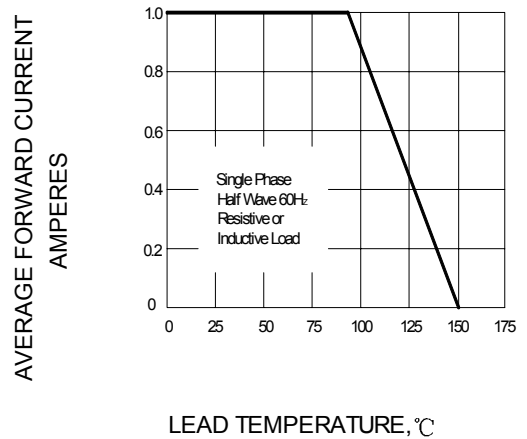
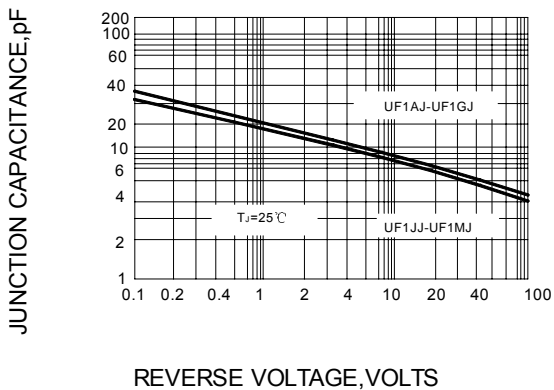
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

Ratings AND Characteristic Curves

FIG.1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC


NOTES:1.RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1MΩ .22pF.
2.RISE TIME =10ns MAX.SOURCE IMPEDANCE=50 Ω.

SET TIME BASE FOR 20/30 ns/cm

FIG.2 – TYPICAL FORWARD CHARACTERISTIC

FIG.3 – FORWARD DERATING CURVE

FIG.4 – TYPICAL JUNCTION CAPACITANCE

FIG.5 – PEAK FORWARD SURGE CURRENT
